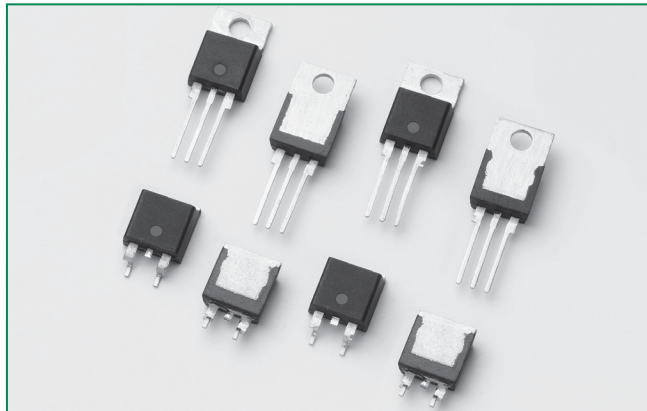


Sxx40x Series

RoHS



**Description**

Excellent unidirectional switches for phase control applications such as heating and motor speed controls. Standard phase control SCRs are triggered with few milliamperes of current at less than 1.5V potential.

**Features & Benefits**

- RoHS compliant
- Glass – passivated junctions
- Voltage capability up to 1000 V
- Surge capability up to 520 A

**Applications**

Typical applications are AC solid-state switches, industrial power tools, exercise equipment, white goods and commercial appliances.

**Main Features**

| Symbol            | Value       | Unit |
|-------------------|-------------|------|
| $I_{T(RMS)}$      | 40          | A    |
| $V_{DRM}/V_{RRM}$ | 400 to 1000 | V    |
| $I_{GT}$          | 40          | mA   |

**Additional Information**



Datasheet

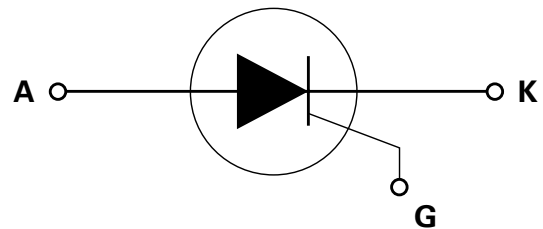


Resources



Samples

**Schematic Symbol**



**Absolute Maximum Ratings**

| Symbol       | Parameter                                 | Test Conditions  | Value      | Unit                   |
|--------------|---|--|------------|------------------------|
| $I_{T(RMS)}$ | RMS on-state current                      | $T_c = 100^\circ\text{C}$  | 40         | A                      |
| $I_{T(AV)}$  | Average on-state current                  | $T_c = 100^\circ\text{C}$  | 25.0       | A                      |
| $I_{TSM}$    | Peak non-repetitive surge current         | single half cycle; $f = 50\text{Hz}$ ;<br>$T_j$ (initial) = $25^\circ\text{C}$ | 430        | A                      |
|              |   | single half cycle; $f = 60\text{Hz}$ ;<br>$T_j$ (initial) = $25^\circ\text{C}$ | 520        |                        |
| $I^2t$       | $I^2t$ Value for fusing                   | $t_p = 8.3 \text{ ms}$   | 1122       | $\text{A}^2\text{s}$   |
| $di/dt$      | Critical rate of rise of on-state current | $f = 60\text{Hz}$ ; $T_j = 125^\circ\text{C}$                                  | 175        | $\text{A}/\mu\text{s}$ |
| $I_{GM}$     | Peak gate current                         | $T_j = 125^\circ\text{C}$  | 3.5        | A                      |
| $P_{G(AV)}$  | Average gate power dissipation            | $T_j = 125^\circ\text{C}$  | 0.8        | W                      |
| $T_{stg}$    | Storage temperature range                 |  | -40 to 150 | $^\circ\text{C}$       |
| $T_j$        | Operating junction temperature range      |  | -40 to 125 | $^\circ\text{C}$       |

### Electrical Characteristics (T<sub>J</sub> = 25°C, unless otherwise specified)

| Symbol          | Test Conditions   |       |      | Value | Unit |
|-----------------|---|-------|------|-------|------|
| I <sub>GT</sub> | V <sub>D</sub> = 12V; R <sub>L</sub> = 30 Ω   |       | MAX. | 40    | mA   |
|                 |   |       | MIN. | 5     |      |
| V <sub>GT</sub> |   |       | MAX. | 1.5   | V    |
| dv/dt           | V <sub>D</sub> = V <sub>DRM</sub> ; gate open; T <sub>J</sub> = 100°C               | 400V  | MIN. | 650   | V/μs |
|                 |   | 600V  |      | 600   |      |
|                 |   | 800V  |      | 500   |      |
|                 |   | 1000V |      | 250   |      |
|                 | V <sub>D</sub> = V <sub>DRM</sub> ; gate open; T <sub>J</sub> = 125°C               | 400V  |      | 550   |      |
|                 |   | 600V  |      | 500   |      |
| 800V            |   | 475   |      |       |      |
| V <sub>GD</sub> | V <sub>D</sub> = V <sub>DRM</sub> ; R <sub>L</sub> = 3.3 kΩ; T <sub>J</sub> = 125°C |       | MIN. | 0.2   | V    |
| I <sub>H</sub>  | I <sub>T</sub> = 400mA (initial)  |       | MAX. | 60    | mA   |
| t <sub>q</sub>  | (1)   |       | MAX. | 35    | μs   |
| t <sub>gt</sub> | I <sub>G</sub> = 2 x I <sub>GT</sub> ; PW = 15μs; I <sub>T</sub> = 80A              |       | TYP. | 2.5   | μs   |

Note :

(1) I<sub>T</sub>=2A; t<sub>p</sub>=50μs; dv/dt=5V/μs; di/dt=-30A/μs

### Static Characteristics

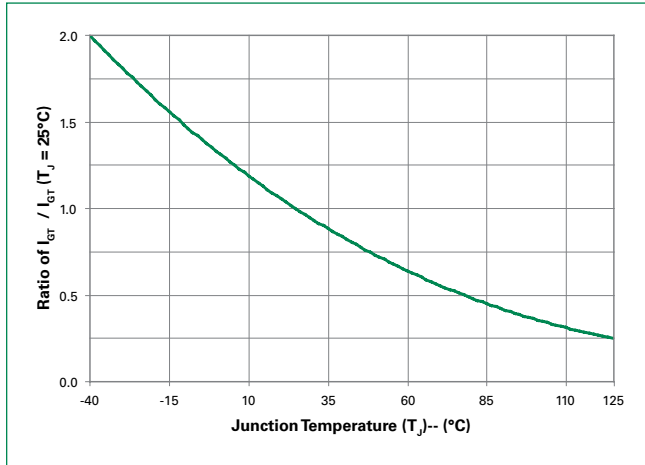
| Symbol                              | Test Conditions                              |                        |            | Value | Unit  |
|-------------------------------------|--|------------------------|------------|-------|-------|
| V <sub>TM</sub>                     | I <sub>T</sub> = 80A; t <sub>p</sub> = 380μs |                        |            | MAX.  | 1.8 V |
| I <sub>DRM</sub> / I <sub>RRM</sub> | V <sub>DRM</sub> / V <sub>RRM</sub>          | T <sub>J</sub> = 25°C  | 400 – 600V | MAX.  | 10    |
|                                     |  |                        | 800 V      |       | 20    |
|                                     |  |                        | 1000 V     |       | 30    |
|                                     |  | T <sub>J</sub> = 100°C | 400 – 600V |       | 1000  |
|                                     |  |                        | 800V       |       | 1500  |
|                                     |  |                        | 1000V      |       | 5000  |
|                                     |  | T <sub>J</sub> = 125°C | 400 – 600V |       | 2000  |
|                                     |  |                        | 800V       |       | 3000  |

### Thermal Resistances

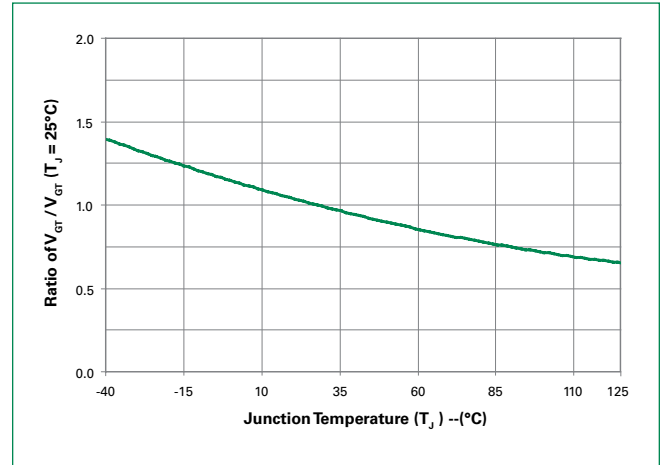
| Symbol              | Parameter             |                 | Value | Unit |
|---------------------|-----------------------|-----------------|-------|------|
| R <sub>θ(J-C)</sub> | Junction to case (AC) | Sxx40R / Sxx40N | 0.6   | °C/W |
| R <sub>θ(J-A)</sub> | Junction to ambient   | Sxx40R          | 40    | °C/W |

Note: xx = voltage

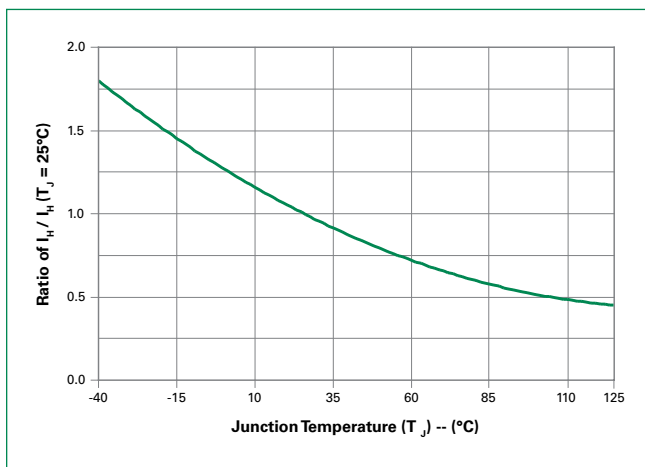
**Figure 1: Normalized DC Gate Trigger Current vs. Junction Temperature**



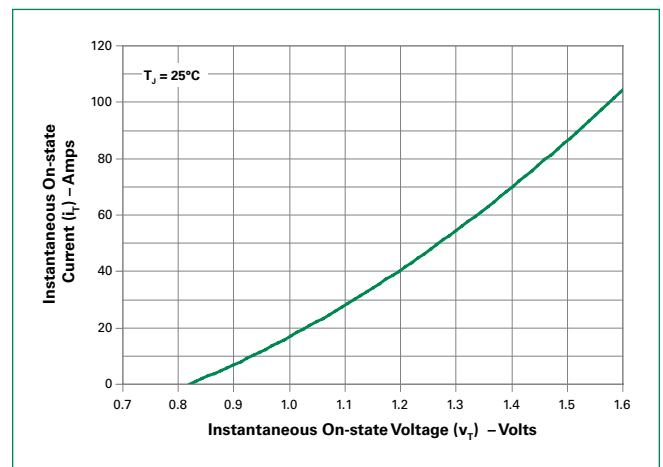
**Figure 2: Normalized DC Gate Trigger Voltage vs. Junction Temperature**



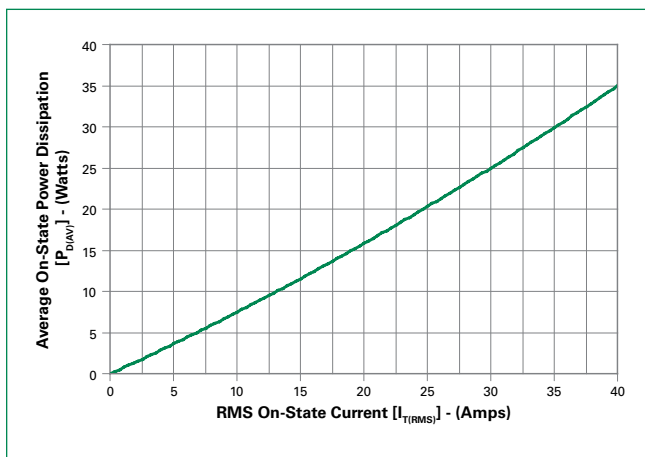
**Figure 3: Normalized DC Holding Current vs. Junction Temperature**



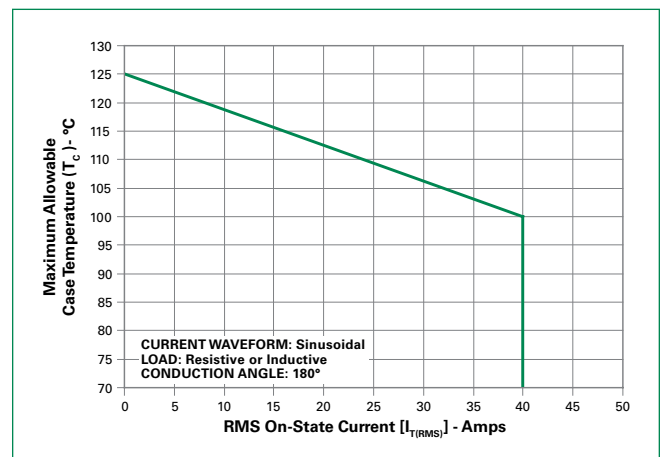
**Figure 4: On-State Current vs. On-State Voltage (Typical)**



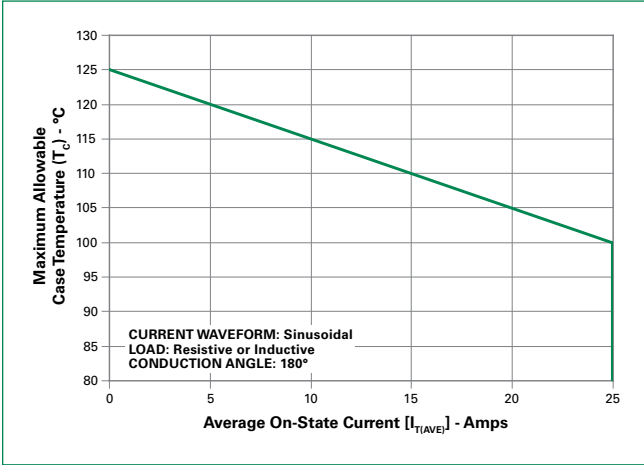
**Figure 5: Power Dissipation (Typical) vs. RMS On-State Current**



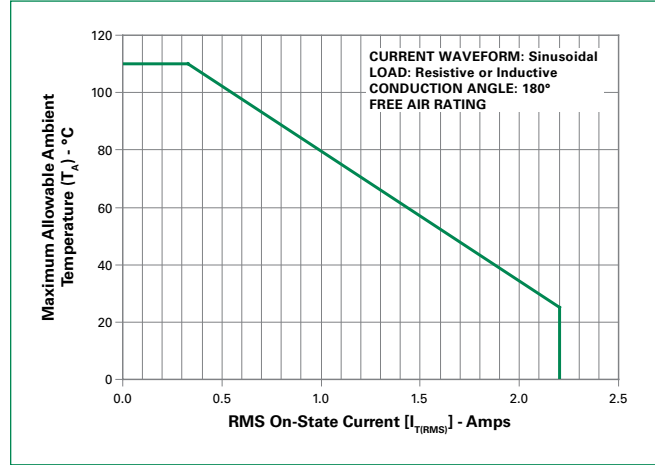
**Figure 6: Maximum Allowable Case Temperature vs. RMS On-State Current**



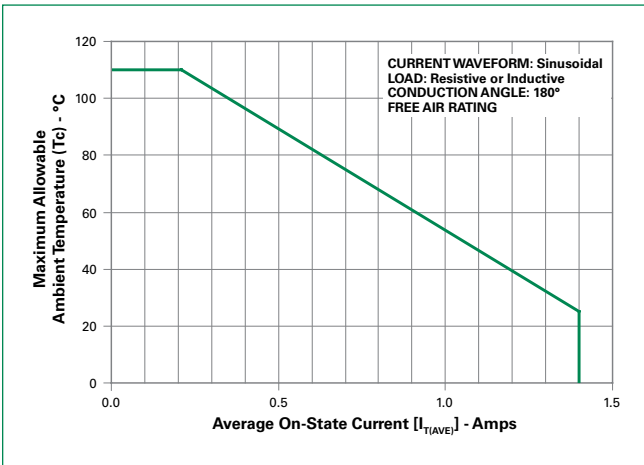
**Figure 7: Maximum Allowable Case Temperature vs. Average On-State Current**



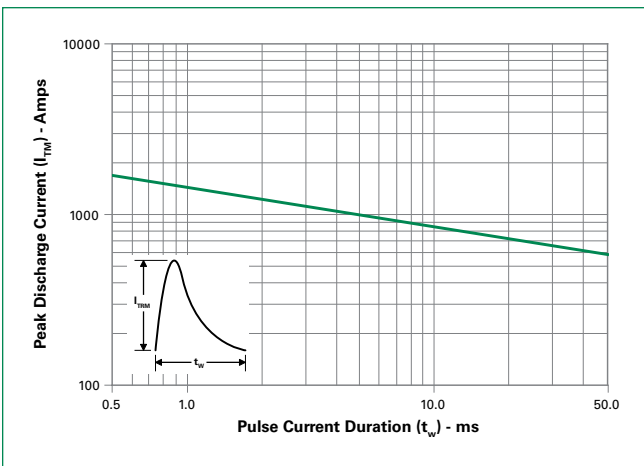
**Figure 8: Maximum Allowable Ambient Temperature vs. RMS On-State Current**



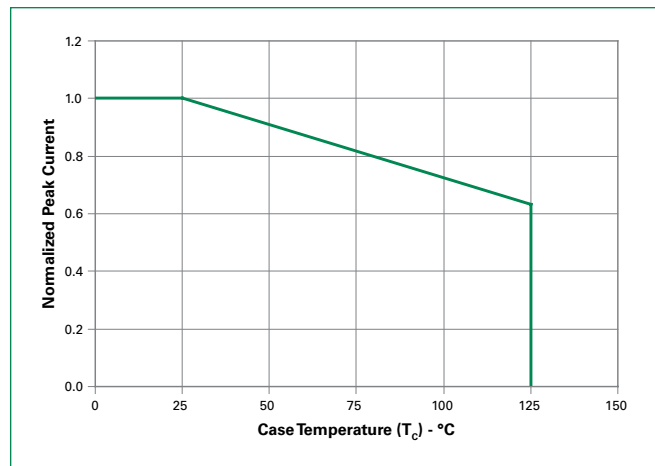
**Figure 9: Maximum Allowable Ambient Temperature vs. Average On-State Current**



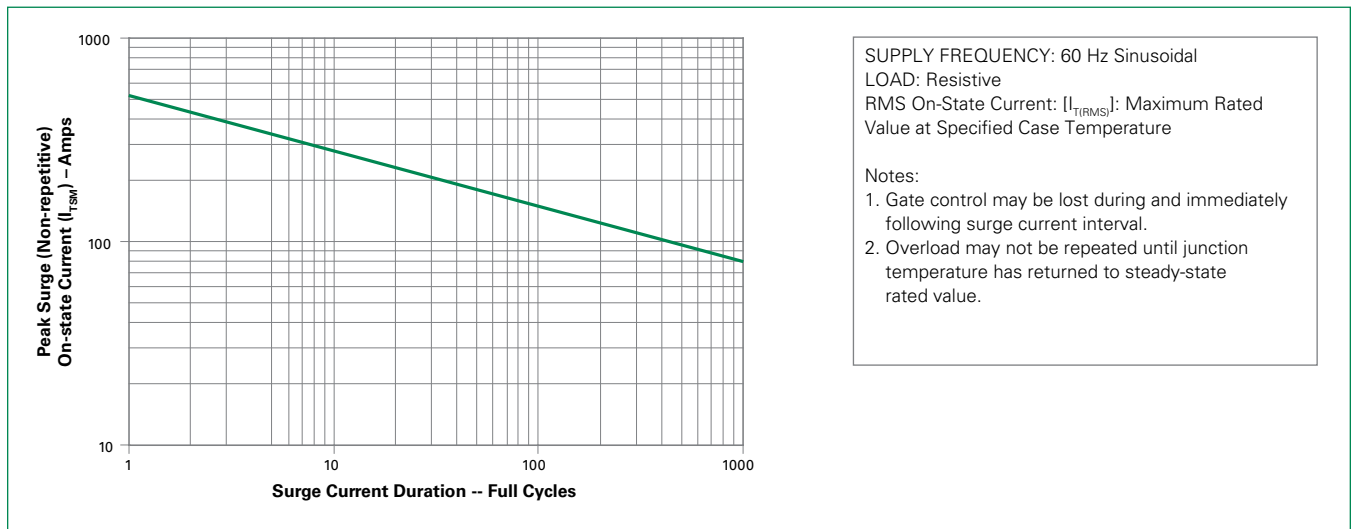
**Figure 10: Peak Capacitor Discharge Current**



**Figure 11: Peak Capacitor Discharge Current Derating**

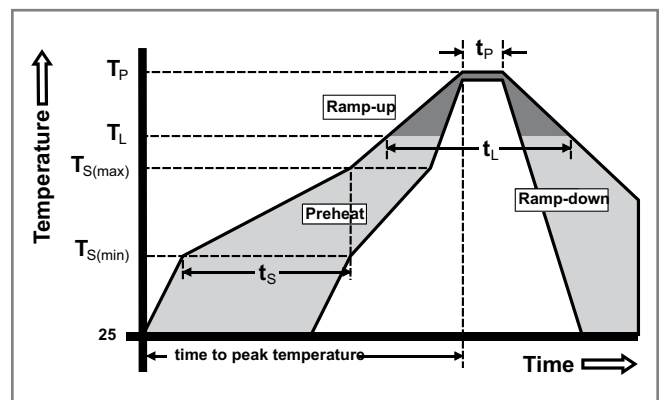


**Figure 12: Surge Peak On-State Current vs. Number of Cycles**



**Soldering Parameters**

|  |                                    |                         |
|--|------------------------------------|-------------------------|
| Reflow Condition                                       |                                    | Pb – Free assembly      |
| Pre Heat   | - Temperature Min ( $T_{s(min)}$ ) | 150°C                   |
|  | - Temperature Max ( $T_{s(max)}$ ) | 200°C                   |
|  | - Time (min to max) ( $t_s$ )      | 60 – 180 secs           |
| Average ramp up rate (Liquidus Temp) ( $T_L$ ) to peak |                                    | 5°C/second max          |
| $T_{s(max)}$ to $T_L$ - Ramp-up Rate                   |                                    | 5°C/second max          |
| Reflow   | - Temperature ( $T_L$ ) (Liquidus) | 217°C                   |
|  | - Temperature ( $t_L$ )            | 60 – 150 seconds        |
| Peak Temperature ( $T_p$ )                             |                                    | 260 <sup>+0/-5</sup> °C |
| Time within 5°C of actual peak Temperature ( $t_p$ )   |                                    | 20 – 40 seconds         |
| Ramp-down Rate   |                                    | 5°C/second max          |
| Time 25°C to peak Temperature ( $T_p$ )                |                                    | 8 minutes Max.          |
| Do not exceed  |                                    | 280°C                   |



### Physical Specifications

|                        |   |
|------------------------|---|
| <b>Terminal Finish</b> | 100% Matte Tin-plated   |
| <b>Body Material</b>   | UL recognized epoxy meeting flammability classification 94V-0 |
| <b>Lead Material</b>   | Copper Alloy  |

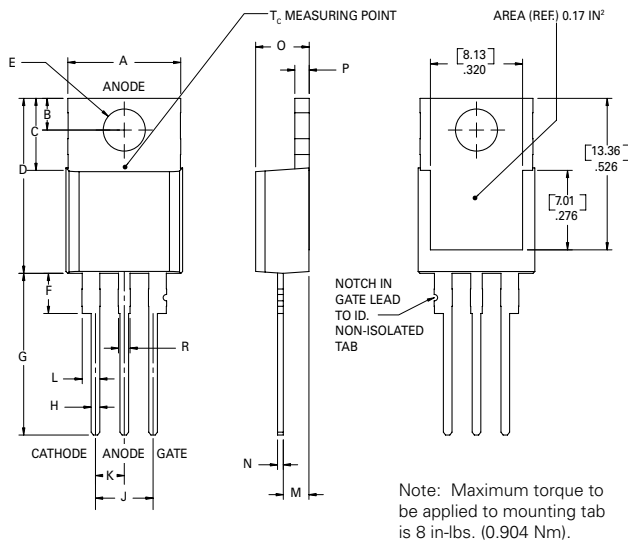
### Design Considerations

Careful selection of the correct device for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Good design practice should limit the maximum continuous current through the main terminals to 75% of the device rating. Other ways to ensure long life for a power discrete semiconductor are proper heat sinking and selection of voltage ratings for worst case conditions. Overheating, overvoltage (including dv/dt), and surge currents are the main killers of semiconductors. Correct mounting, soldering, and forming of the leads also help protect against component damage.

### Environmental Specifications

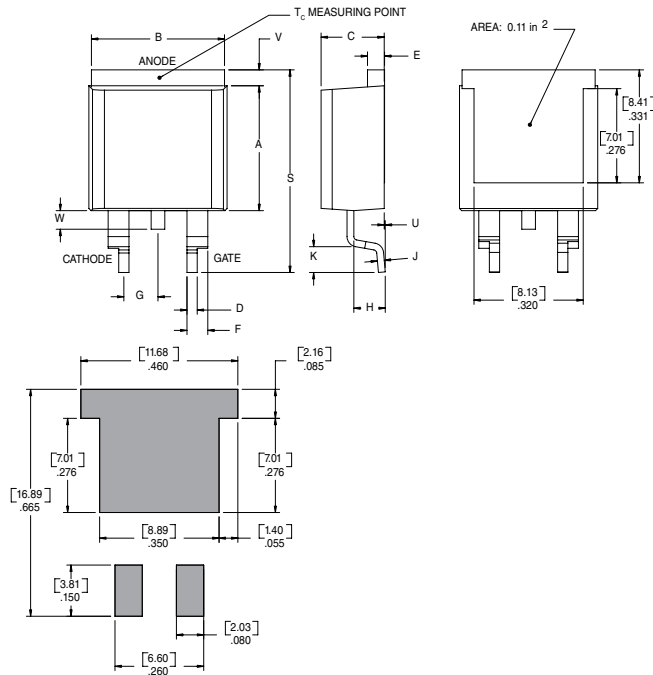
| Test                             | Specifications and Conditions  |
|----------------------------------|--|
| <b>AC Blocking</b>               | MIL-STD-750, M-1040, Cond A Applied Peak AC voltage @ 125°C for 1008 hours   |
| <b>Temperature Cycling</b>       | MIL-STD-750, M-1051, 100 cycles; -40°C to +150°C; 15-min dwell-time  |
| <b>Temperature/Humidity</b>      | EIA / JEDEC, JESD22-A101 1008 hours; 320V - DC: 85°C; 85% rel humidity   |
| <b>High Temp Storage</b>         | MIL-STD-750, M-1031, 1008 hours; 150°C   |
| <b>Low-Temp Storage</b>          | 1008 hours; -40°C  |
| <b>Thermal Shock</b>             | MIL-STD-750, M-1056 10 cycles; 0°C to 100°C; 5-min dwelltime at each temperature; 10 sec (max) transfer time between temperature |
| <b>Autoclave</b>                 | EIA / JEDEC, JESD22-A102 168 hours (121°C at 2 ATMs) and 100% R/H  |
| <b>Resistance to Solder Heat</b> | MIL-STD-750 Method 2031  |
| <b>Solderability</b>             | ANSI/J-STD-002, category 3, Test A   |
| <b>Lead Bend</b>                 | MIL-STD-750, M-2036 Cond E   |

### Dimensions — TO-220AB (R-Package) — Non-Isolated Mounting Tab Common with Center Lead



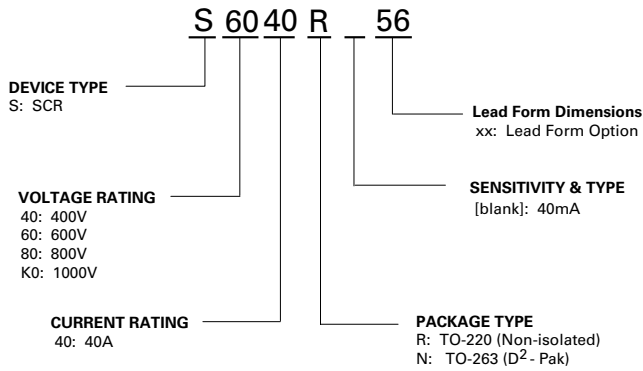
| Dimension | Inches |       | Millimeters |       |
|-----------|--------|-------|-------------|-------|
|           | Min    | Max   | Min         | Max   |
| A         | 0.380  | 0.420 | 9.65        | 10.67 |
| B         | 0.105  | 0.115 | 2.67        | 2.92  |
| C         | 0.230  | 0.250 | 5.84        | 6.35  |
| D         | 0.590  | 0.620 | 14.99       | 15.75 |
| E         | 0.142  | 0.147 | 3.61        | 3.73  |
| F         | 0.110  | 0.130 | 2.79        | 3.30  |
| G         | 0.540  | 0.575 | 13.72       | 14.61 |
| H         | 0.025  | 0.035 | 0.64        | 0.89  |
| J         | 0.195  | 0.205 | 4.95        | 5.21  |
| K         | 0.095  | 0.105 | 2.41        | 2.67  |
| L         | 0.060  | 0.075 | 1.52        | 1.91  |
| M         | 0.085  | 0.095 | 2.16        | 2.41  |
| N         | 0.018  | 0.024 | 0.46        | 0.61  |
| O         | 0.178  | 0.188 | 4.52        | 4.78  |
| P         | 0.045  | 0.060 | 1.14        | 1.52  |
| R         | 0.038  | 0.048 | 0.97        | 1.22  |

**Dimensions – TO- 263 (N-package) – D<sup>2</sup>-Pak Surface Mount**



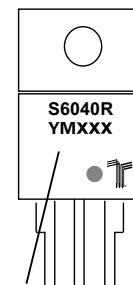
| Dimension | Inches |       | Millimeters |       |
|-----------|--------|-------|-------------|-------|
|           | Min    | Max   | Min         | Max   |
| A         | 0.360  | 0.370 | 9.14        | 9.40  |
| B         | 0.380  | 0.420 | 9.65        | 10.67 |
| C         | 0.178  | 0.188 | 4.52        | 4.78  |
| D         | 0.025  | 0.035 | 0.63        | 0.89  |
| E         | 0.048  | 0.055 | 1.22        | 1.40  |
| F         | 0.060  | 0.075 | 1.52        | 1.91  |
| G         | 0.095  | 0.105 | 2.41        | 2.67  |
| H         | 0.083  | 0.093 | 2.11        | 2.36  |
| J         | 0.018  | 0.024 | 0.46        | 0.61  |
| K         | 0.090  | 0.110 | 2.29        | 2.79  |
| S         | 0.590  | 0.625 | 14.99       | 15.87 |
| V         | 0.035  | 0.045 | 0.89        | 1.14  |
| U         | 0.002  | 0.010 | 0.05        | 0.25  |
| W         | 0.040  | 0.070 | 1.02        | 1.78  |

**Part Numbering System**



**Part Marking System**

TO-220 AB - (R Package)  
TO-263 AB - (N Package)



**Date Code Marking**  
Y: Year Code  
M: Month Code  
XXX: Lot Trace Code

**Product Selector**

| Part Number | Voltage |      |      |       | Gate Sensitivity | Type         | Package |
|-------------|---------|------|------|-------|------------------|--------------|---------|
|             | 400V    | 600V | 800V | 1000V |                  |              |         |
| Sxx40R      | X       | X    | X    | X     | 40mA             | Standard SCR | TO-220R |
| Sxx40N      | X       | X    | X    | X     | 40mA             | Standard SCR | TO-263  |

Note: xx = Voltage

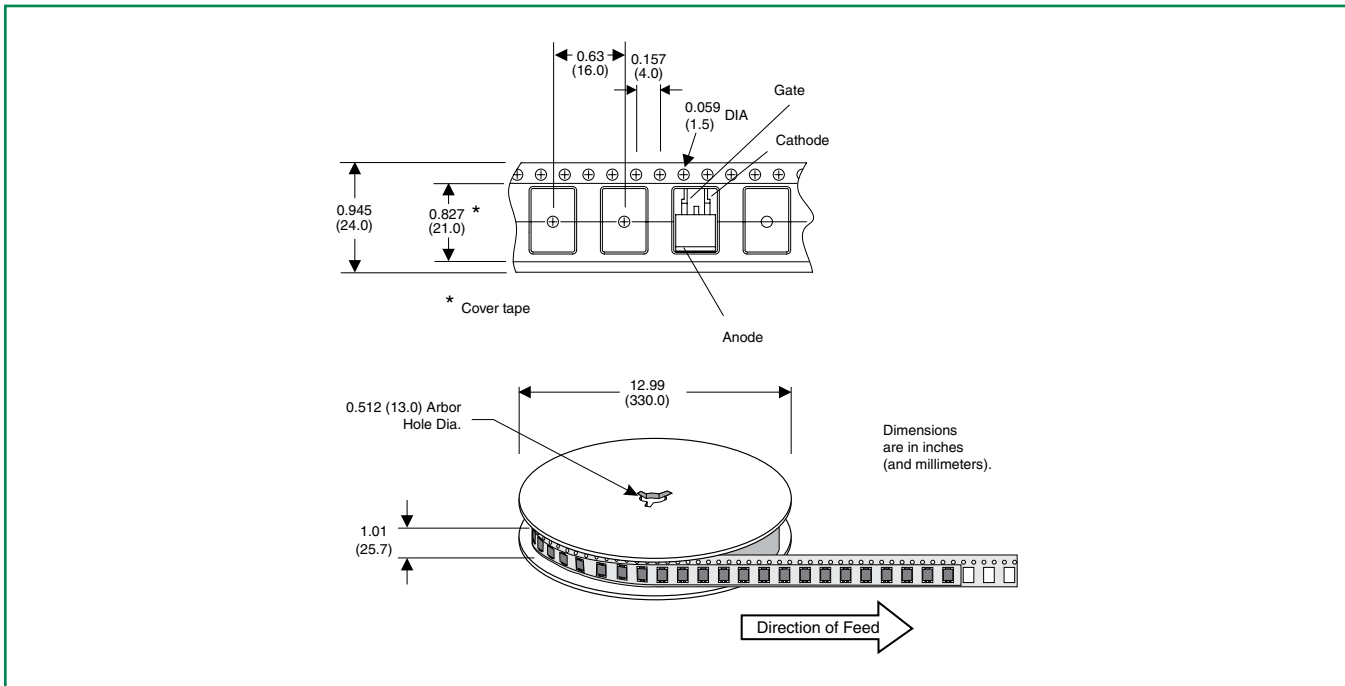
**Packing Options**

| Part Number | Marking | Weight | Packing Mode     | Base Quantity     |
|-------------|---------|--------|------------------|-------------------|
| Sxx40R      | Sxx40R  | 2.2g   | Bulk             | 500               |
| Sxx40RTP    | Sxx40R  | 2.2g   | Tube             | 500 (50 per tube) |
| Sxx40NTP    | Sxx40N  | 1.6g   | Tube             | 500 (50 per tube) |
| Sxx40NRP    | Sxx40N  | 1.6g   | Embossed Carrier | 500               |

Note: xx = Voltage

**Reel Pack (RP) for TO-263 Embossed Carrier Specifications**

**Meets all EIA-481-2 Standards**





Компания «Океан Электроники» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Поставка оригинальных импортных электронных компонентов напрямую с производств Америки, Европы и Азии, а так же с крупнейших складов мира;
- Широкая линейка поставок активных и пассивных импортных электронных компонентов (более 30 млн. наименований);
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Компания «Океан Электроники» является официальным дистрибьютором и эксклюзивным представителем в России одного из крупнейших производителей разъемов военного и аэрокосмического назначения «JONHON», а так же официальным дистрибьютором и эксклюзивным представителем в России производителя высокотехнологичных и надежных решений для передачи СВЧ сигналов «FORSTAR».



## JONHON

«JONHON» (основан в 1970 г.)

Разъемы специального, военного и аэрокосмического назначения:

(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

«FORSTAR» (основан в 1998 г.)

ВЧ соединители, коаксиальные кабели, кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).



Телефон: 8 (812) 309-75-97 (многоканальный)

Факс: 8 (812) 320-03-32

Электронная почта: [ocean@oceanchips.ru](mailto:ocean@oceanchips.ru)

Web: <http://oceanchips.ru/>

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, д. 2, корп. 4, лит. А